# NSN 5962-00-216-4144

Memory Microcircuit - Page 1 of 1



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# **Body Outside Diameter:**

Between 0.335 inches and 0.370 inches

# **Body Height:**

Between 0.165 inches and 0.185 inches

# **Maximum Power Dissipation Rating:**

500.0 milliwatts

#### **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

# Storage Tempurature Range:

-65.0/+150.0 degrees celsius

# **Features Provided:**

Monolithic and hermetically sealed and negative outputs and positive outputs and w/field effect transistor switch and internally compensated

#### **Inclosure Material:**

Glass and metal

#### **Inclosure Configuration:**

# Can

**Input Circuit Pattern:** 

2 input

# **Case Outline Source And Designator:**

T0-99 joint electron device engineering council

# **Terminal Surface Treatment:**

Solder

# Voltage Rating And Type Per Characteristic:

15.0 volts power source

# **Time Rating Per Chacteristic:**

300.00 nanoseconds propagation delay time, low to high level output

# Memory Device Type:

Rom

# **Terminal Type And Quantity:**

8 pin

#### Shelf Life:

N/a

# Unit Of Measure:

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# **Demilitarization:**

Yes - demil/mli

Fiig:

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